

RoHS Compliant Product

Description

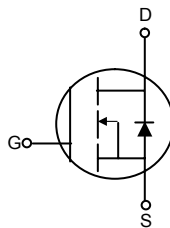
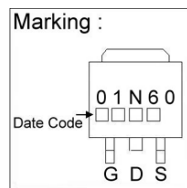
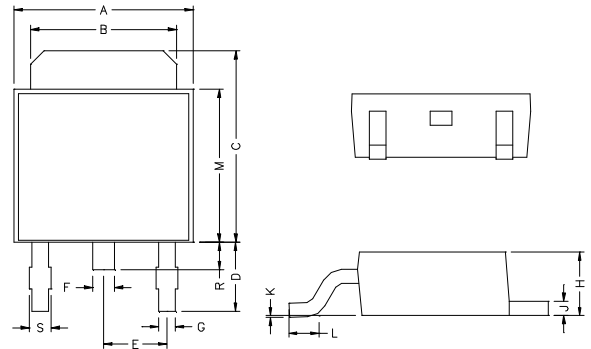
The SSD01N60 provide the designer with the best combination of fast switching.

The TO-252 is universally preferred for all commercial-industrial surface mount applications and suited for AC/DC converters.

Features

- * Dynamic dv/dt Rating
- * Simple Drive Requirement
- * Fast Switching
- * Repetitive Avalanche Rated

TO-252



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	6.40	6.80	G	0.50	0.70
B	5.20	5.50	H	2.20	2.40
C	6.80	7.20	J	0.45	0.55
D	2.20	2.80	K	0	0.15
E	2.30 REF.		L	0.90	1.50
F	0.70	0.90	M	5.40	5.80
S	0.60	0.90	R	0.80	1.20

Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V_{DS}	600	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current, $V_{GS}@10V$	$I_D@T_C=25^\circ C$	1.6	A
Continuous Drain Current, $V_{GS}@10V$	$I_D@T_C=100^\circ C$	1	A
Pulsed Drain Current ¹	I_{DM}	6	A
Total Power Dissipation	$P_D@T_C=25^\circ C$	39	W
Linear Derating Factor		0.31	W/ $^\circ C$
Single Pulse Avalanche Energy ²	E_{AS}	13	mJ
Avalanche Current	I_{AR}	1.6	A
Repetitive Avalanche Energy	E_{AR}	0.5	mJ
Operating Junction and Storage Temperature Range	T_j, T_{stg}	-55~+150	$^\circ C$

Thermal Data

Parameter	Symbol	Ratings	Unit
Thermal Resistance Junction-case	R_{thj-c}	3.2	$^\circ C/W$
Thermal Resistance Junction-ambient	R_{thj-a}	110	$^\circ C/W$

Electrical Characteristics(T_j=25°C Unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Drain-Source Breakdown Voltage	BV _{DSS}	600	–	–	V	V _{GS} =0V, I _D =250μA
Breakdown Voltage Temp. Coefficient	ΔBV _{DSS} /ΔT _j	–	0.6	–	V/°C	Reference to 25°C, I _D =1mA
Gate Threshold Voltage	V _{GS(th)}	2.0	–	4.0	V	V _{DS} =V _{GS} , I _D =250μA
Gate-Source Leakage Current	I _{GSS}	–	–	±100	nA	V _{GS} =±20V
Drain-Source Leakage Current (T _j =25°C)	I _{DSS}	–	–	100	μA	V _{DS} =600V, V _{GS} =0
Drain-Source Leakage Current(T _j =150°C)		–	–	500	μA	V _{DS} =480V, V _{GS} =0
Static Drain-Source On-Resistance	R _{DS(ON)}	–	7.2	8.0	Ω	V _{GS} =10V, I _D =0.8A
Forward Transconductance	G _{fs}	–	0.8	–	S	V _{DS} =50V, I _D =0.8A
Total Gate Charge ³	Q _g	–	7.7	–	nC	I _D =1.6A V _{DS} =480V V _{GS} = 10V
Gate-Source Charge	Q _{gs}	–	1.5	–		
Gate-Drain ("Miller") Charge	Q _{gd}	–	2.6	–		
Turn-on Delay Time ³	T _{d(ON)}	–	8	–	nS	V _{DD} =300V I _D =1.6A V _{GS} =10V R _G =10 Ω R _D =187.5 Ω
Rise Time	T _r	–	5	–		
Turn-off Delay Time	T _{d(OFF)}	–	14	–		
Fall Time	T _f	–	7	–		
Input Capacitance	C _{iss}	–	286	–	pF	V _{GS} =0V V _{DS} =25V f=1.0MHz
Output Capacitance	C _{oss}	–	25	–		
Reverse Transfer Capacitance	C _{rss}	–	5	–		

Source-Drain Diode

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Forward On Voltage ³	V _{SD}	–	–	1.5	V	I _S =1.6A, V _{GS} =0V, T _j =25°C
Continuous Source Current(Body Diode)	I _S	–	–	1.6	A	V _D =V _G =0V, V _S =1.5 V
Pulsed Source Current(Body Diode) ¹	I _{SM}	–	–	6	A	

Notes: 1. Pulse width limited by safe operating area.

2. Starting T_j=25°C, V_{DD}=50V, L=10mH, R_G=25Ω, I_{AS}=1.6A.

3. Pulse width ≤ 300μs, duty cycle ≤ 2%.

Characteristics Curve

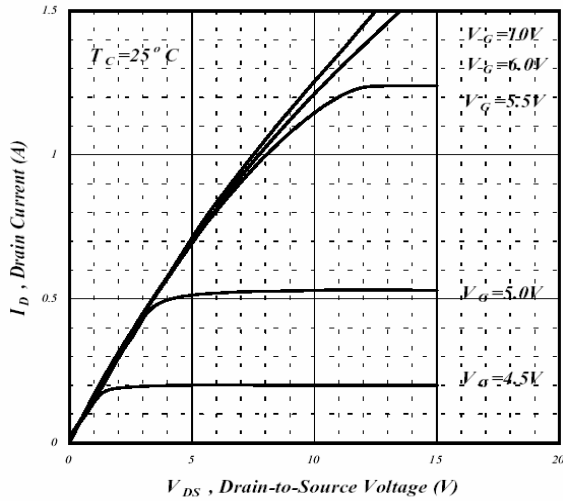


Fig 1. Typical Output Characteristics

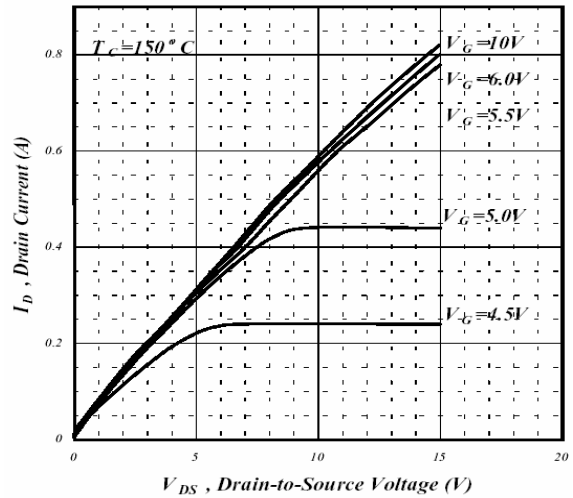


Fig 2. Typical Output Characteristics

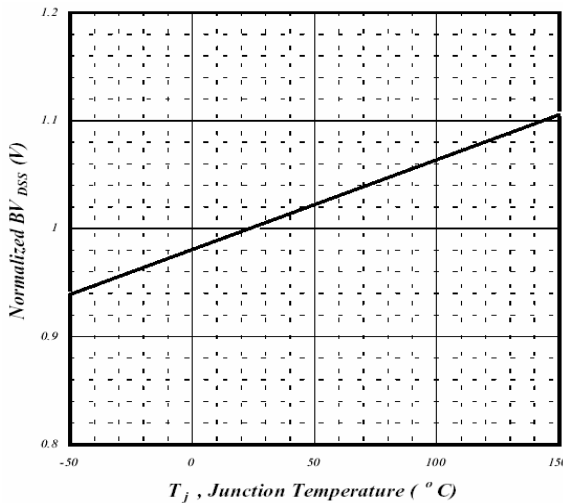


Fig 3. Normalized BV_{DSS} v.s. Junction Temperature

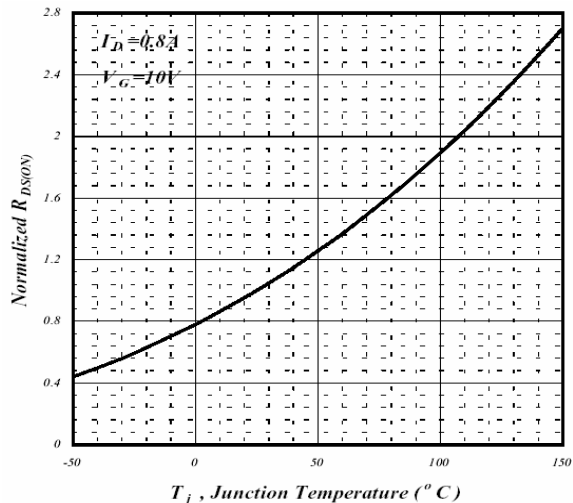


Fig 4. Normalized On-Resistance v.s. Junction Temperature

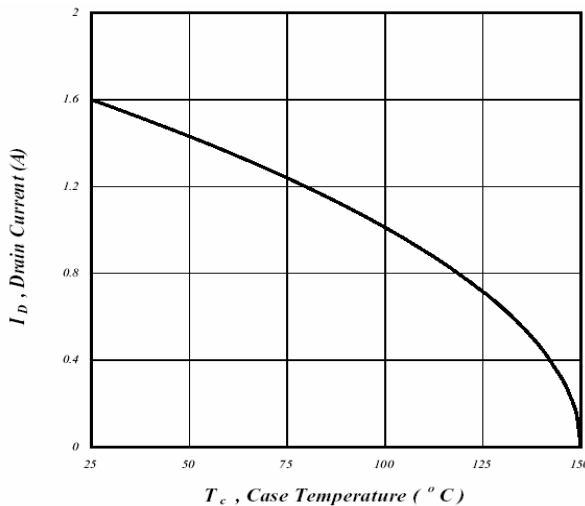


Fig 5. Maximum Drain Current v.s. Case Temperature

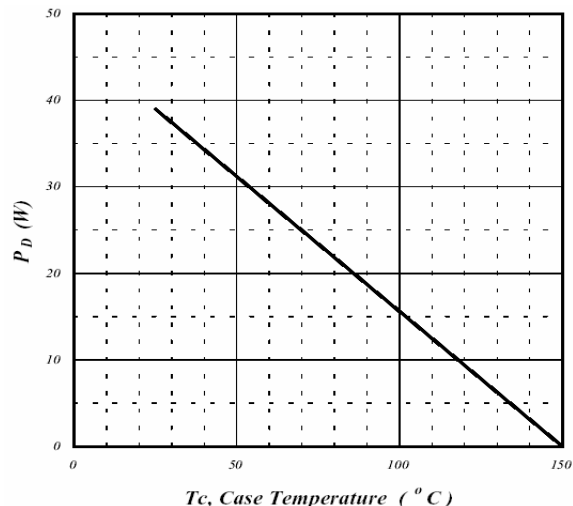


Fig 6. Type Power Dissipation

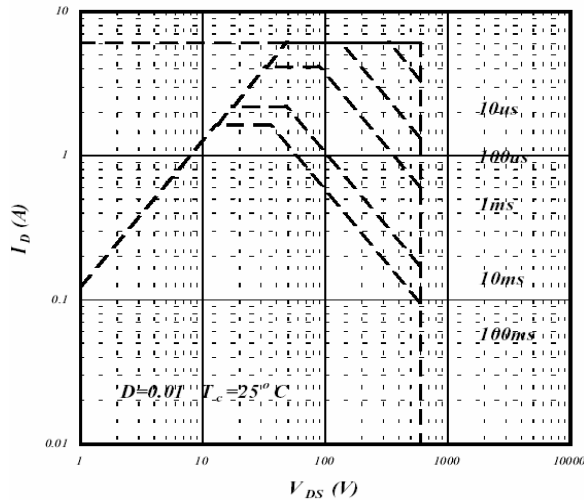


Fig 7. Maximum Safe Operating Area

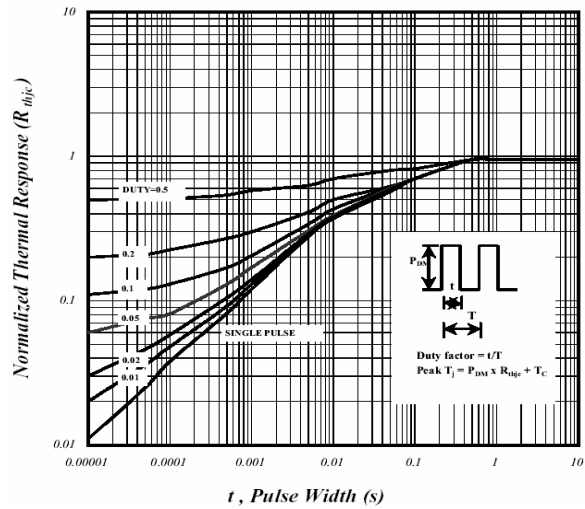


Fig 8. Effective Transient Thermal Impedance

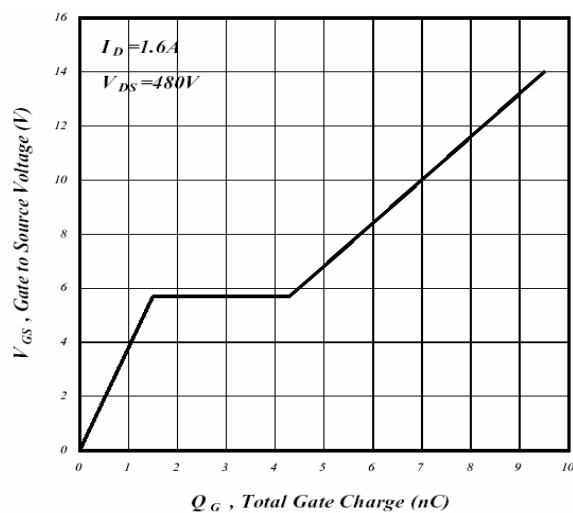


Fig 9. Gate Charge Characteristics

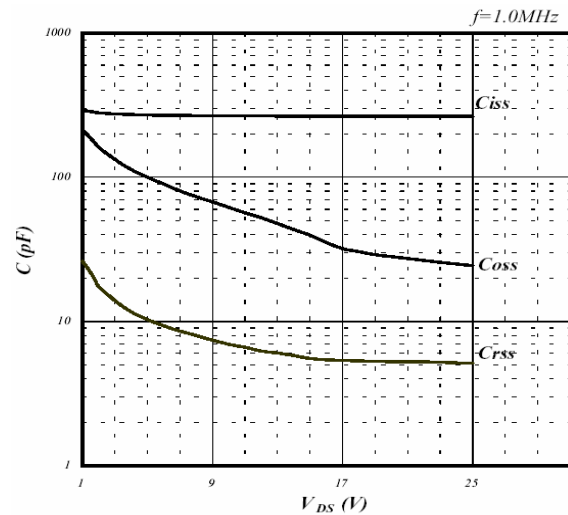


Fig 10. Typical Capacitance Characteristics

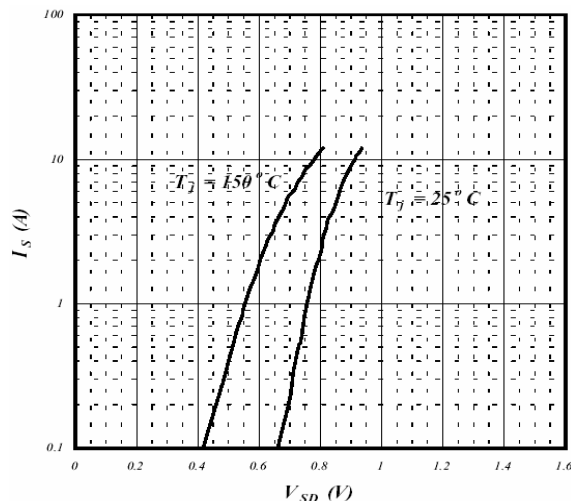


Fig 11. Forward Characteristics of Reverse Diode

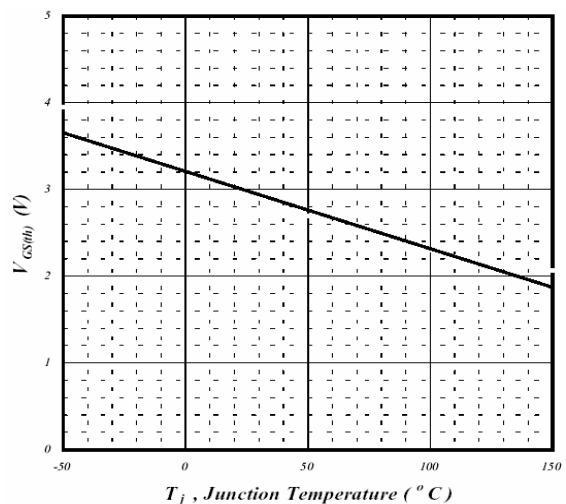


Fig 12. Gate Threshold Voltage v.s. Junction Temperature

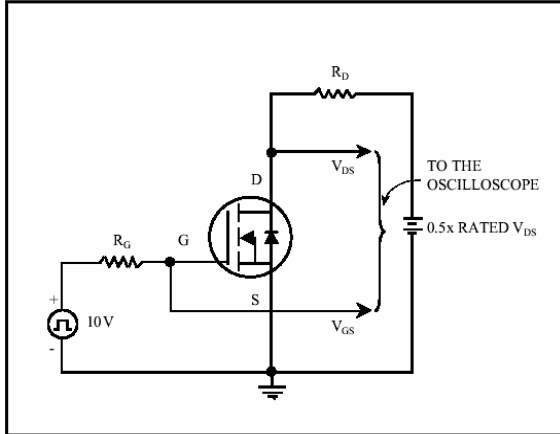


Fig 13. Switching Time Circuit

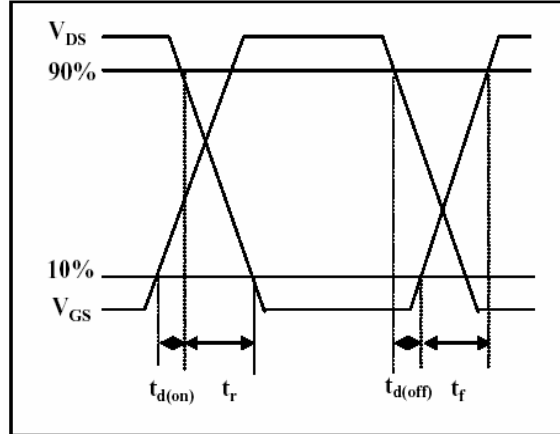


Fig 14. Switching Time Waveform

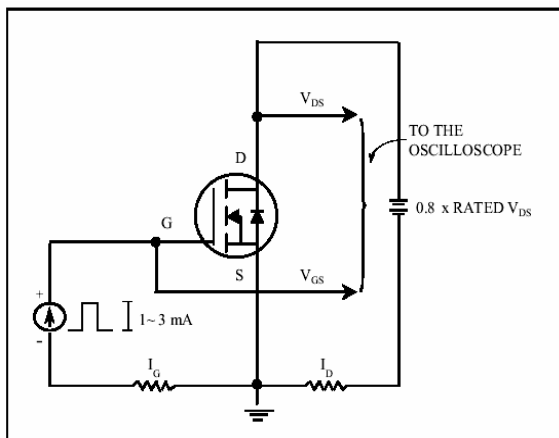


Fig 15. Gate Charge Circuit

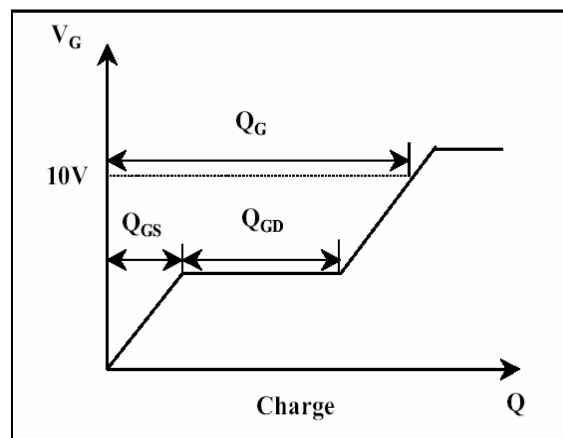


Fig 16. Gate Charge Waveform